

CMR COLLEGE OF ENGINEERING & TECHNOLOGY (UGC AUTONOMOUS)

B.Tech III Semester Supplementary Examinations February-2024

Course Name: NUMERICAL MATHODS & COMPLEX VARIABLES

(Common for EEE & ECE)

Time: 3 hours Date: 05.02.2024 AN (Note: Assume suitable data if necessary)

PART-A

Answer all TEN questions (Compulsory)

Each question carries TWO marks.

10x2 = 20M

Max.Marks: 70

1.	Find $L\{\sin 3t + e^{-2t} + t^3\}$	2 M
2.	State Convolution in Laplace transforms.	2 M

Prove $\delta E^{\frac{1}{2}} = \Delta$ 3.

2 M

Write Central difference formula. 4.

2 M

Formula for Simpson's 3/8th rule by taking n=6 5.

2 M

 $\frac{dy}{dx} = 3x^2 + 1$, y(1) = 2, find y(1.5) using Euler's method, h=0.5 6.

2 M

Is $f(z) = |z|^2$ is analytic? 7.

2 M

Real and imaginary parts of Sinz? 8.

2 M

Find the singularities of the function $f(z) = \frac{z}{(z^2+1)(z-2)}$ 9.

2 M

Taylor's series of $f(z) = \cos z$ at z = 0

2 M

PART-B

Answer the following. Each question carries TEN Marks.

5x10=50M

- 5M i) Find the Laplace transform of the full-wave rectifier, $f(t) = E \sin \omega t$, $0 < t < \frac{\pi}{\omega}$, 11.A). having period $\frac{\pi}{\omega}$.
 - ii) Find $L^{-1}\left\{log\left(\frac{s+a}{s+b}\right)\right\}$

5M

OR

11. B). Using L.T method, Solve $(D^2 + \alpha^2)x = asin(\alpha t + 2)$, x = Dx = 0 at t = 0.

10M

i) Find by Gauss Backward interpolating formula the value of y at x = 1936 using the 12. A). following data

7M

1911 1921 1931 1941 1951 1901 X 39 52 12 15 20 27

У

3M

ii) Evaluate f(10) given f(x) = 168,192,336 at x = 1,7,15 respectively. Use Lagrange interpolation.

OR

Find the root of the equation $cos x = xe^x$ using the Regula-falsi method correct to four 10M decimal places.

(P.T.O..)

13. A). i) Solve $y' = x^2 - y$, y(0) = 1 Using Taylor's series method and compute y(0.1)6M correct to 4 decimal places. ii) Evaluate $\int_0^1 \frac{1}{1+x} dx$ using Simpson's 1/3 rule and compare the result with its actual 4M value. OR 13. B). Using R-K method of fourth order, find y(0.2) & y(0.4) given that $\frac{dy}{dx} = \frac{y^2 - x^2}{y^2 + x^2}$, with 10M y(0)=1,i) Find the analytic function, whose real part is $\frac{\sin 2x}{(\cosh 2y - \cos 2x)}$. 6M ii) Find the real and imaginary parts of cotz. 4M 14. B). i) Find all the values of $\left(\frac{\sqrt{3}}{2} + \frac{i}{2}\right)^{(1+i\sqrt{3})}$ 5M 5M ii) Show that the real and imaginary parts of an analytic function are harmonic. 15. A). i) Evaluate $\int_{1-i}^{2+i} (2x + 1 + iy) dz$ along (1-i) to (2+i)5M ii) Expand $f(z) = \frac{1}{z^2 - 3z + 2}$ in the range 1 < |z| < 2. 5M

15. B). Evaluate $\oint_C \frac{z-3}{z^2+2z+5} dz$, where 'c' is the circle given by (i) |z| = 1(ii) |z+1-i| = 2 (iii) |z+1+i| = 2.



CMR COLLEGE OF ENGINEERING & TECHNOLOGY (UGC AUTONOMOUS)

B.Tech III Semester Supplementary Examinations February-2024

Course Name: ELECTRICAL ENGINEERING

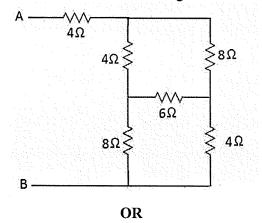
(Electronics & Communication Engineering) Time: 3 hours Max.Marks: 70 Date: 07.02.2024 AN (Note: Assume suitable data if necessary) PART-A Answer all TEN questions (Compulsory) Each question carries TWO marks. 10x2 = 20MDefine Active element and Passive element. 2 M 1. 2. State Maximum Power transfer theorem. 2 M List out the advantages of three phase system over single-phase system. 2 M 3. 4. Draw the phasor diagram of the series RL circuit. 2 M 5. 2 M What is transient? 6. Define time constant of RL circuit. 2 M 7. Write the formulae of Eddy current and hysteresis losses of Transformer. 2 M 8. Define voltage regulation of a transformer. 2 M 9. Write the merits and demerits of slip-ring induction motor. 2 M 10. List out the application of types of DC Motor. 2 M

PART-B Answer the following. Each question carries TEN Marks.

5x10=50M

11.A). Find the equivalent resistance between A & B in the given network.

10M



11. B). State & very Superposition theorem.

10M

12. A). Derive the RMS value and average value of an alternating quantity.

10M

OR

12. B). Derive the relationship between line and phase quantities in a 3-phase balanced:

10M

- i) Star connected system
- ii) Delta connected system

(P.T.O..)

A series RL circuit has R= 25 Ω and L = 5 Henry. A dc voltage V of 100 V is applied to 10M this circuit at t = 0 secs. Find: (a) The equations for the charging current, and voltage across R & L (b) The current in the circuit 0.5 secs after the voltage is applied. (c) The time at which the drops across R and L are equal. Determine Y parameters interns of ABCD Parameters. 13. B). 10M 14. A). Explain the working principal of a single-phase Transformer. 10M The voltage per turn of a single-phase transformer is 1.1V. when the primary winding is 14. B). 10M connected to a 220V, 50Hz A.C. supply, the secondary voltage is found to be 550V. Find i) Primary and secondary turns. ii) Core area if the maximum flux density is 1.1T. 15. A). Explain the working principle of 3 phase Induction Motor. 10M A 6-pole lap wound dc shunt motor has 250 armature conductors, a flux of 0.04 wb/pole 10M and runs at 1200 rpm. The armature and field winding resistances are 1 ohm and 220 ohms respectively. It is connected to a 220-v dc supply. Determine: i) induced emf in the motor, ii) armature current, iii) input supply current, iv) mechanical power and v) torque developed.

,	H.T No: R18 Course Code: A304	02
	CMR COLLEGE OF ENGINEERING & TECHNOLOGY (UGC AUTONOMOUS)	
	B. Tech III Semester Supplementary Examinations February-2024	
	Course Name: PROBABILITY & STOCHASTIC PROCESSES (Electronics & Communication Engineering)	
,	Date: 09.02.2024 AN Time: 3 hours Max.Mark	s: 70
	(Note: Assume suitable data if necessary)	
	PART-A Answer all TEN questions (Compulsory)	
		=20M
1.	What are the Axioms of probability?	2 M
2.	Write short notes on classification of random variables.	2 M
3.	A random variable X has PDF $(x) = e^{ax}$, Solve for its mean?	2 M
4.	A random variable X has PDF $f(x) = 6x - 6x^2$ for $0 \le x \ge 1$. Solve for the constant b such that $P(X \le b) = P(X \ge b)$.	2 M
5.	Let X and Y be joint continuous random variable with joint pdf $f(xy) = 2$ for $0 < x, y < 1$, Estimate the marginal density function of X.	2 M
6.	Let X and Y be joint continuous random variable with joint pdf	2 M
	$f(xy) = \begin{cases} e^{-x} & \text{for } 0 < x < y \\ 0 & \text{otherwise} \end{cases}$ Estimate $f_Y(y)$	
7.	State the properties of auto correlation.	2 M
8.	Define Wide Sense Stationary.	2 M
9.	Define the properties of PSD.	2 M
10.	What is the IFT($S_{XY}(w)$)?	2 M
	PART-B	
	Answer the following. Each question carries TEN Marks. 5x10=	=50M
11.A	suffering from a certain disease, and a probability 0.10 of giving a (false) positive when applied to a non-sufferer. It is estimated that 0.5 % of the population are sufferers.	10M
	Suppose that the test is now administered to a person about	
	whom we have no relevant information relating to the disease (apart from the fact that	
	he/she comes from this	
	population). Calculate the following probabilities:	
	(i) that the test result will be positive;	
	(ii) that, given a positive result, the person is a sufferer;	
	(iii) that, given a negative result, the person is a non-sufferer;(iv) that the person will be misclassified	
	OD	

10M

(P.T.O..)

11. B). Define conditional probability and prove bayes theorem.

12. A). For real constant
$$b > 0$$
, $c > 0$ and any 'a' find a condition on constant 'a' such that the function $f_X(x) = \left\{ a \left\{ 1 - \frac{x}{b} \right\} \text{ for } 0 \le x \le c \right\}$, is a valid probability density 0 otherwise

10M

12. B). Find the mean and mean square value of Gaussian distribution.

10M

10M

A₁,A₂,A₃ are mutually exclusively events associated with a random experiment E1. Events B₁,B₂,B₃ are mutually exclusively events associated with a random experiment E2 the joint probabilities of occurrence of these events and some marginal probabilities are listed in the table given below (a) find the missing probabilities in the table (b) find P(B₃/A₁) an P(A₁/B₃) (c) are events A₁, B₁ are statistically independent

	B1	B2	В3
A1	3/36	*	5/36
A2	5/36	4/36	5/36
A3	*	6/36	*
P(BJ)	12/36	14/36	*

OR

Two random variables X and Y having joint probability density function 13. B).

10M

$$f(xy) = \begin{cases} e^{-(x+y)} for \ x, y \ge 0 \\ 0 \quad otherwise \end{cases}$$
 find

a) marginal density function of X and Y

b) $P(X \le 1, Y \le 1)$ and $P(X+Y \le 1)$ also prove that X and Y are independent random variable

State and prove the properties of cross correlation?

15. A).

10M

OR

14. B). If $X(t)=\cos(wt+Y)$, where Y is a random variable distributed uniformly over $(0, 2\pi)$ 10M determine whether X(t) is Wide Sense Stationary.

10M

Consider a linear system with transform function $H(w) = \frac{1}{6+jw}X(t)$ is the input and Y(t)is the output of the system . the auto correlation of x(t) is RXX(τ)=3 δ (t).Find the PSD ,auto correlation function and mean square value of the output Y(t)

State and prove the properties of Cross Power Density Spectrum.

10M

OR

(ii) J-K flip-flop to S-R flip-flop

10M

(P.T.O..)

1.

2.

3.

4.

5.

6.

remedy for it.

13. B).

Convert the following flip-flops.

(i) S-R flip-flop to J-K flip-flop

14. A).	Distinguish between synchronous and async	chronous counters with an example for each.	10M
14. B).	OR Construct mod-3-bit Up-Down synchronous counter using J-K flip flops.		1017
			10M
15. A).	Explain capabilities and limitations of finite state machines.		10M
15. B).	Explain the following:	OR	
	i) Silont facture CAGAGA	ii) Binary Multiplier	10M



CMR COLLEGE OF ENGINEERING & TECHNOLOGY

(UGC AUTONOMOUS)

	Con	B.Tech III Semester Supplementary Examinations February-2024 urse Name: ELECTRONIC DEVICES & CIRCUITS	
	Cot	(Common for EEE & ECE)	
	Date	e: 14.02.2024 AN Time: 3 hours Max.Marks	: 70_
		(Note: Assume suitable data if necessary) PART-A	
		Answer all TEN questions (Compulsory) Each question carries TWO marks. 10x2=2	20M
1.		r what voltage will the reverse current in p-n junction Germanium diode reach 90% of its uration value at room temperature?	2 M
2.	De	scribe the V-I characteristics of varactor diode.	2 M
3.	Ex	plain how to reduce harmonics in rectifier circuit	2 M
4.	De	fine peak inverse voltage and why is it important?	2 M
5.	Gi	ve the advantages of h-parameter analysis	2 M
6.	Ex	plain the base spreading resistance.	2 M
7.	De	fine operating point of a transistor and mention its purpose	2 M
8.	Ex	plain thermal stability and what does it represent	2 M
9.	De	efine transconductance and drain resistance of a FET.	2 M
10		r a p-channel Silicon FET, with effective width 'a'= $2X10^{-4}$ cm and channel resistivity =10 Ω . Solve for the pinch off voltage.	2 M
	Ans	PART-B swer the following. Each question carries TEN Marks. 5x10=	50M_
1	 1.A).	 i) Define and derive the expression for transition capacitance of a PN junction diode. ii) Explain two-transistor analogy of SCR with its equivalent circuit diagram and characteristics. 	5M 5M
		OR	
1	1. B).	i) Explain the working of a semiconductor photo diode. Mention its applications.ii) Define and distinguish PN diode and Zener diode. Discuss different breakdown mechanisms in Zener diode.	5M 5M
1:	2. A).	i) With the help of a circuit diagram and waveforms, explain the operation of Full wave rectifier with capacitor filter and derive the expression for its ripple factor.	5M
		ii) Define and compare inductor and capacitor filters.	5M
11	2. B).	OR i) A half wave rectifier has a load of 3.5 K Ω . If the diode resistance and the secondary	5M
	2. D).	coil resistance together have a resistance of 800Ω and the input voltage has a signal voltage of 240 V, measure i) Peak, average and rms value of current flowing. ii) dc power output. iii) ac power input iv) Efficiency of the rectifier.	3101
		ii) With suitable wave forms and circuit diagram explain bridge rectifier.	5M
		$(\mathbf{p} \ \mathbf{r} \ \mathbf{o})$	

(P.T.O..)

13. 2	its applications. working and characteristics of UJT with a diagram. List	5M
	ii) Draw the circuit diagram of an NPN junction transistor in CE configuration and describe its characteristics. Explain how CE acta as an amplifier.	5M
	OP	
13. E	 i) Discuss, how the h-parameters are determined from transistor Characteristics. ii) Explain the input and output characteristics of the transistor in CC configuration with diagrams. 	5M 5M
14. A). i) Define and derive the stability of	
	The dolly die stability factor of ton collect	5M
	ii) Explain diode compensation technique for the parameters of $V_{\rm BE}$ and $I_{\rm CO}$	5M
14. B	α	3171
14. D	i) Draw the DC load line and obtain quiescent point for the transistor shown below.	
	V _{CC} = +12 V	5M
	$R_{B1} = 5.2 \text{ k}\Omega$ $V_{I} \circ \qquad V_{O}$ $C_{I} \circ \qquad V_{O}$ $R_{B2} = 1.24 \text{ k}\Omega$ $R_{E} = 100 \Omega$ $R_{E} = 100 \Omega$	
	ii) Draw and explain the Fixed Bias Circuit. Explain why the circuit is unsatisfactory if the transistor is replaced by another of same type	5M
15. A).	 i) Describe the operation of common drain FET amplifier and derive the equation for voltage gain. ii) Explain the working of a depletion type MOSFET with a neat construction diagram and its characteristics. 	5M
	the tis characteristics.	5M
15. B).	i) Explain the IEEE a	
- · -),	i) Explain the JFET Small signal Model. What is its use?	
	ii) Derive the expression for the width of depletion region 'W' in the case of p-channel JFET.	5M
	m the case of p-channel	5M